## NSN 5961-00-905-8499

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View Online at https://aerobasegroup.com/nsn/5961-00-905-8499 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.210 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage, dc all transistor and 60.0 collector to emitter voltage/static/base open all transistor and 6.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 0.6 watts small-signal input power, common-collector all transistor **Transfer Ratio:** 40.0 static forward current transfer ratio, common-emitter all transistor **Special Features:** All transistor junction pattern arrangement: npn **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 6 uninsulated wire lead

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N/a

Shelf Life:

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

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